

Erratum

Suppression of the “notch effect” in microwave surface resistance in $\text{YBa}_2\text{Cu}_3\text{O}_7$ films on MgO (100) substrate by deposition of ultra-thin SrTiO_3 seed layers

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Figures 7a and 7b were exchanged with Figures 7c1 and 7c2. Figure 7 should be replaced by the following.

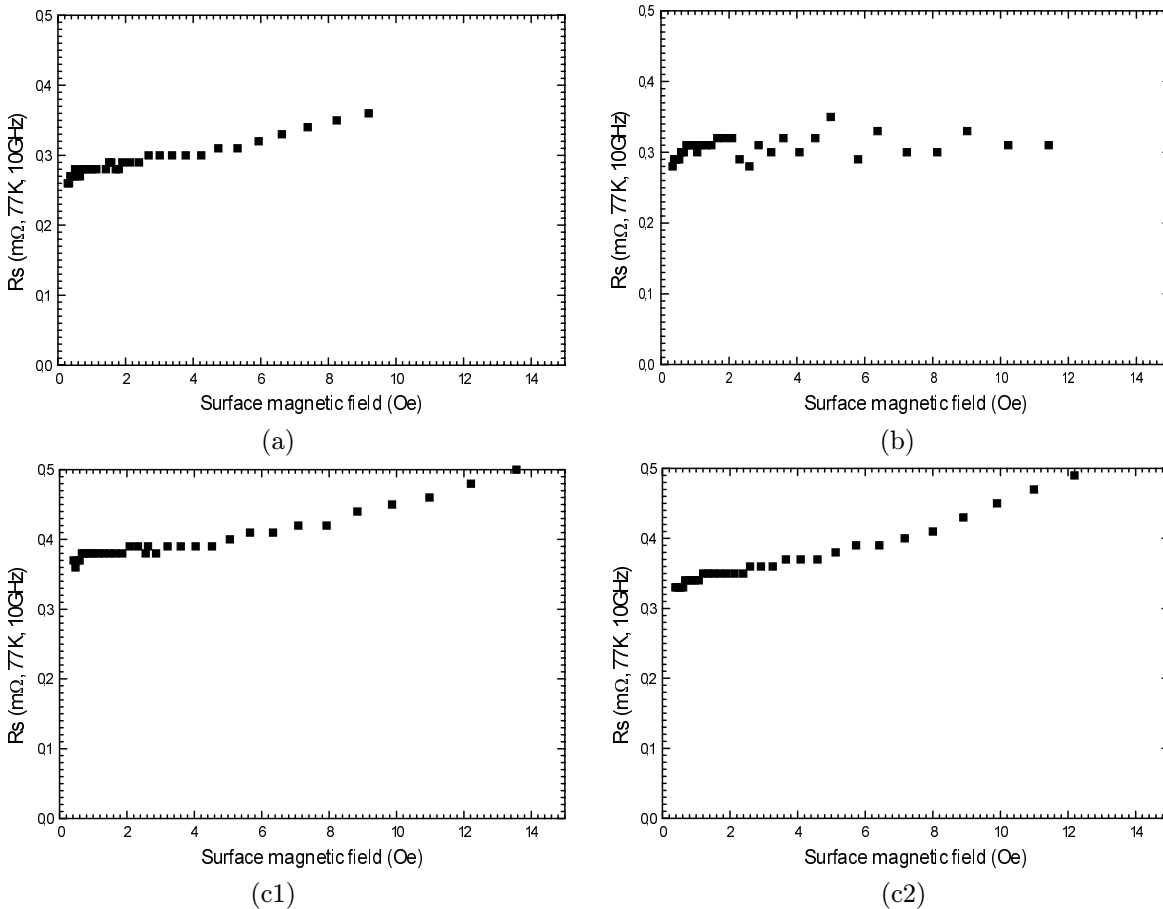


Fig. 7. Surface resistance (10 GHz, 77 K) of the YBCO layer as a function of the RF field: (a) 400 nm on LaAlO_3 grown by PLD; (b) 400 nm on a 12 cell buffer layer on (100) MgO ; (c) double sided (side 1 and 2) film on LaAlO_3 grown by DC hollow cathode sputtering.